



#### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
201/	0.9Ω @ V <sub>GS</sub> = -10V	-0.55A
-30V	1.7Ω @ V <sub>GS</sub> = -4.5V	-0.4A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Motor controls
- Power management functions
- DC-DC converters

## **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP31D7LDWQ)

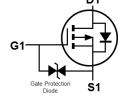
### **Mechanical Data**

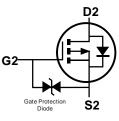
- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.027 grams (Approximate)

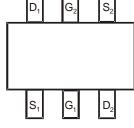












Top View

Q1 P-Channel

Q2 P-Channel

Top View Pin Out

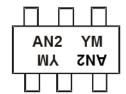
### **Ordering Information** (Note 4)

Part Number	mhor	Pookogo	Pac	king	
Fait Nu	Part Number Package		Qty.	Carrier	
DMP31D7	LDW-7	SOT363	3,000	Tape & Reel	
DMP31D7	LDW-13	SOT363	10,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



AN2= Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  or  $\underline{Y}$ = Year (ex: J = 2022) M = Month (ex: 9 = September)

Data Coda Kay

Year	2019		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	G		J	K	L	M	Ν	0	Р	R	S	T
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



## **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage				-30	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ΙD	-0.55 -0.44	Α
Maximum Continuous Body Diode Forward Current (Note 6)	Is	-0.38	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	-2.4	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

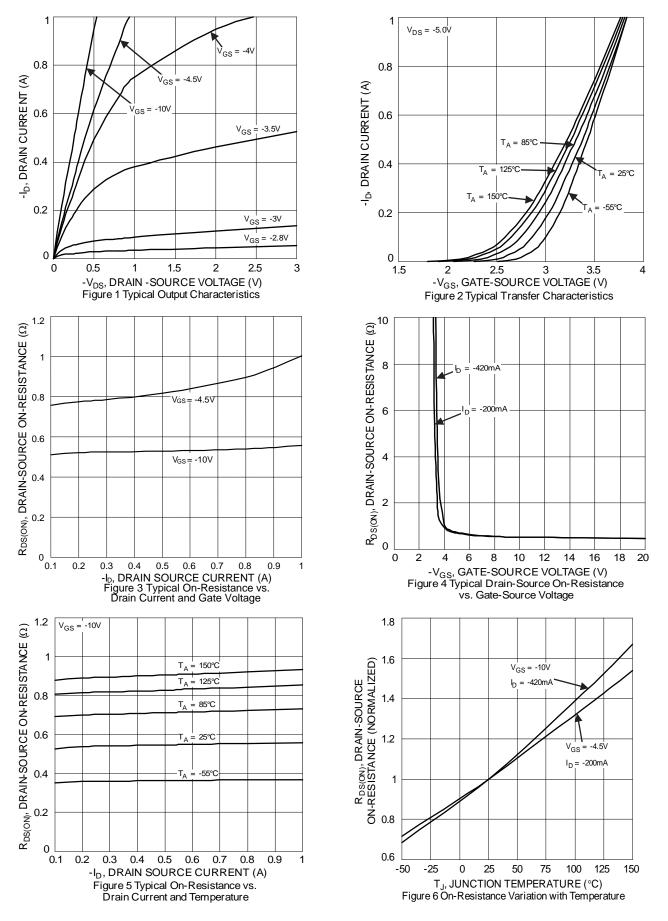
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.29	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	433	°C/W
Total Power Dissipation (Note 6)		PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rөja	301	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics – P Channel (@T<sub>A</sub> = +25°C, unless otherwise specified.)

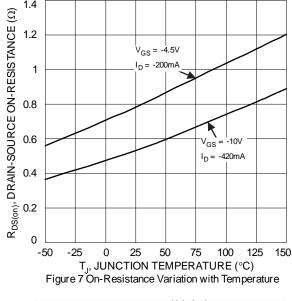
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	٧	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS		_	-1	μΑ	V <sub>DS</sub> = -24V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>		_	±10	μΑ	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	-1	-2.2	-2.6	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
Static Drain-Source On-Resistance	Process		0.5	0.9	Ω	$V_{GS} = -10V, I_D = -0.42A$
Static Drain-Source On-Resistance	RDS(ON)		0.78	1.7	12	$V_{GS} = -4.5V$ , $I_{D} = -0.2A$
Diode Forward Voltage	VsD	_	-0.8	-1.2	V	$V_{GS} = 0V$ , $I_{S} = -0.23A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>		19	_	pF	151/1/ 21/
Output Capacitance	Coss		16	_	рF	V <sub>DS</sub> = -15V, V <sub>GS</sub> = 0V, -f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3	_	pF	1 = 1.0WH 12
Gate Resistance	Rg	_	729	_	Ω	$V_{DS} = V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (VGS = -4.5V)	Qg		0.36	_	nC	
Total Gate Charge (VGS = -10V)	Qg		0.8	_	nC	\/ 10\/ I= 0.24A
Gate-Source Charge	Qgs		0.1	_	nC	$V_{DS} = -10V, I_{D} = -0.24A$
Gate-Drain Charge	$Q_{gd}$		0.1	_	nC	
Turn-On Delay Time	tD(ON)		30	_	ns	
Turn-On Rise Time	t <sub>R</sub>		74	_	ns	$V_{GS} = -10V, V_{DD} = -15V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		28	_	ns	$I_D = -0.5A, R_G = 1\Omega$
Turn-Off Fall Time	tF		31	_	ns	

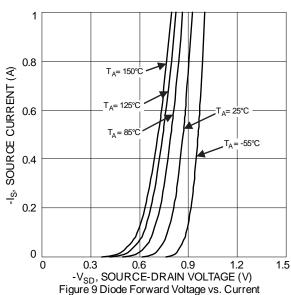
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
  Device mounted on FR-4 substrate PC board, 2oz copper, with 1in square copper plate.
  Short duration pulse test used to minimize self-heating effect.
  Guaranteed by design. Not subject to product testing.

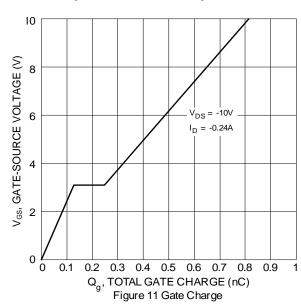












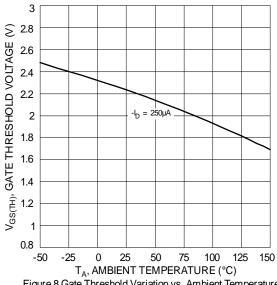
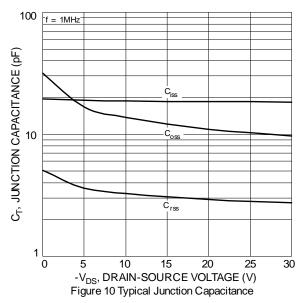
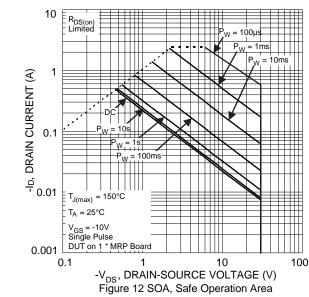
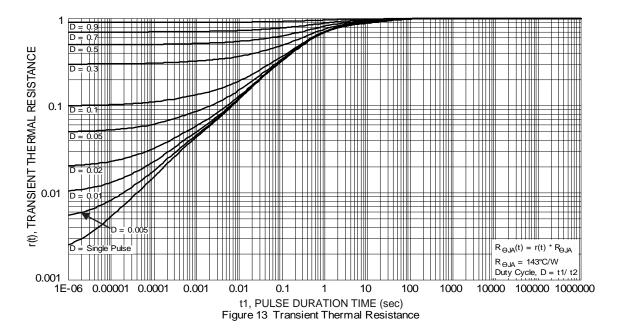


Figure 8 Gate Threshold Variation vs. Ambient Temperature





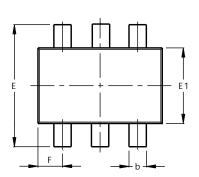


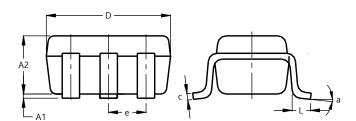




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





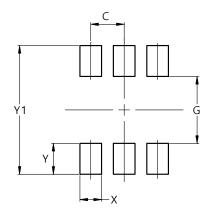
	SOT363							
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.10	0.30	0.25					
С	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	0.650 BSC						
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All I	Dimen	sions	in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT363

**SOT363** 



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2 500



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